

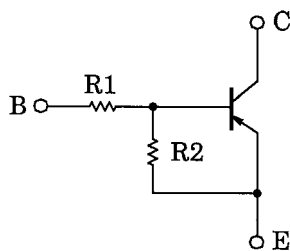
TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

RN2607,RN2608,RN2609

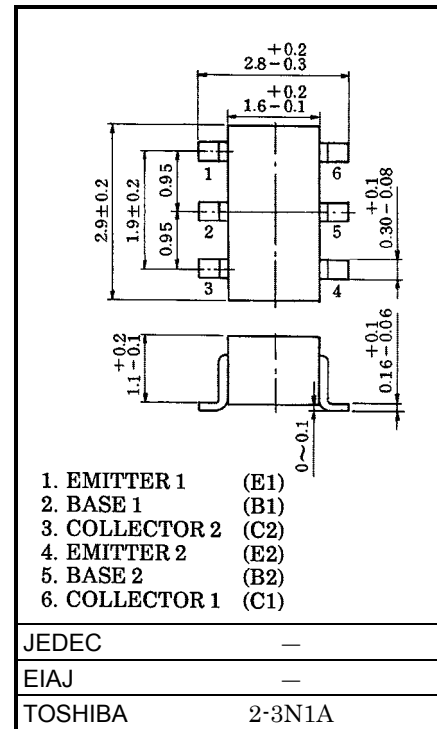
Switching, Inverter Circuit, Interface Circuit
And Driver Circuit Applications

- Including two devices in SM6 (super mini type with 6 leads)
- With built-in bias resistors
- Simplify circuit design
- Reduce a quantity of parts and manufacturing process
- Complementary to RN1607~RN1609

Equivalent Circuit and Bias Resistor Values



Type No.	R1 (kΩ)	R2 (kΩ)
RN2607	10	47
RN2608	22	47
RN2609	47	22

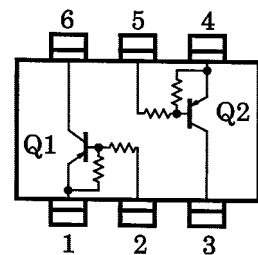


Equivalent Circuit (Top View)

Maximum Ratings (Ta = 25°C)

Characteristic	Symbol	Rating	Unit
Collector-base voltage	V_{CBO}	-50	V
Collector-emitter voltage	V_{CEO}	-50	V
Emitter-base voltage	V_{EBO}	-6	V
		-7	
		-15	
Collector current	I_C	-100	mA
Collector power dissipation	P_C^*	300	mW
Junction temperature	T_j	150	°C
Storage temperature range	T_{stg}	-55~150	°C

* Total rating



Electrical Characteristics (Ta = 25°C) (Q1, Q2 Common)

Characteristic		Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Collector cut-off current	RN2607~RN2609	I_{CBO}	—	$V_{CB} = -50V, I_E = 0$	—	—	-100	nA
		I_{CEO}	—	$V_{CE} = -50V, I_B = 0$	—	—	-500	nA
Emitter cut-off current	RN2607	I_{EBO}	—	$V_{EB} = -6V, I_C = 0$	-0.081	—	-0.15	mA
	RN2608		—	$V_{EB} = -7V, I_C = 0$	-0.078	—	-0.145	
	RN2609		—	$V_{EB} = -15V, I_C = 0$	-0.167	—	-0.311	
DC current gain	RN2607	h_{FE}	—	$V_{CE} = -5V, I_C = -10mA$	80	—	—	—
	RN2608		—		80	—	—	
	RN2609		—		70	—	—	
Collector-emitter saturation voltage	RN2607~RN2609	$V_{CE(sat)}$	—	$I_C = -5mA, I_B = -0.25mA$	—	-0.1	-0.3	V
Input voltage (ON)	RN2607	$V_{I(ON)}$	—	$V_{CE} = -0.2V, I_C = -5mA$	-0.7	—	-1.8	V
	RN2608		—		-1.0	—	-2.6	
	RN2609		—		-2.2	—	-5.8	
Input voltage (OFF)	RN2607	$V_{I(OFF)}$	—	$V_{CE} = -5V, I_C = -0.1mA$	-0.5	—	-1.0	V
	RN2608		—		-0.6	—	-1.16	
	RN2609		—		-1.5	—	-2.6	
Translation frequency	RN2607~RN2609	f_T	—	$V_{CE} = -10V, I_C = -5mA$	—	200	—	MHz
Collector output capacitance	RN2607~RN2609	C_{ob}	—	$V_{CB} = -10V, I_E = 0$ $f = 1MHz$	—	3	6	pF
Input resistor	RN2607	R1	—	—	7	10	13	kΩ
	RN2608		—		15.4	22	28.6	
	RN2609		—		32.9	47	61.1	
Resistor ratio	RN2607	R1/R2	—	—	0.191	0.213	0.232	—
	RN2608		—		0.421	0.468	0.515	
	RN2609		—		1.92	2.14	2.35	

(Q1, Q2 Common)

